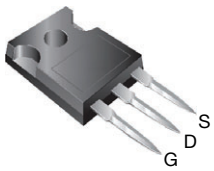
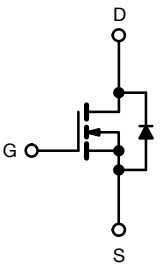
# Power MOSFET

TO-247AC




N-Channel MOSFET

## FEATURES

- Superfast body diode eliminates the need for external diodes in ZVS applications
- Lower gate charge results in simpler drive requirements
- Enhanced dV/dt capabilities offer improved ruggedness
- Higher gate voltage threshold offers improved noise immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Available

RoHS* Available

## APPLICATIONS

- Zero voltage switching SMPS
- Telecom and server power supplies
- Uninterruptible power supplies
- Motor control applications

**Note**

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

| PRODUCT SUMMARY | | |
|---|---|---|
| $V_{DS}$ (V) | 500 | |
| $R_{DS(on)}$ (Ω) | $V_{GS}$ = 10 V | 0.190 |
| $Q_g$ max. (nC) | 150 | |
| $Q_{gs}$ (nC) | 44 | |
| $Q_{gd}$ (nC) | 72 | |
| Configuration | Single | |

| ORDERING INFORMATION | |
|---|---|
| Package | TO-247AC |
| Lead (Pb)-free | IRFP23N50LPbF |

**ABSOLUTE MAXIMUM RATINGS** ($T_C$ = 25 °C, unless otherwise noted)

| PARAMETER | | | SYMBOL | LIMIT | UNIT |
|---|---|---|---|---|---|
| Drain-source voltage | | | $V_{DS}$ | 500 | V |
| Gate-source voltage | | | $V_{GS}$ | ± 30 | |
| Continuous drain current | $V_{GS}$ at 10 V | $T_C$ = 25 °C | $I_D$ | 23 | A |
| | | $T_C$ = 100 °C | | 15 | |
| Pulsed drain current [a] | | | $I_{DM}$ | 92 | |
| Linear derating factor | | | | 2.9 | W/°C |
| Single pulse avalanche energy [b] | | | $E_{AS}$ | 410 | mJ |
| Repetitive avalanche current [a] | | | $I_{AR}$ | 23 | A |
| Repetitive avalanche energy [a] | | | $E_{AR}$ | 37 | mJ |
| Maximum power dissipation | $T_C$ = 25 °C | | $P_D$ | 370 | W |
| Peak diode recovery dV/dt [c] | | | dV/dt | 21 | V/ns |
| Operating junction and storage temperature range | | | $T_J$, $T_{stg}$ | -55 to +150 | °C |
| Soldering recommendations (peak temperature) [d] | for 10 s | | | 300 | |
| Mounting torque | 6-32 or M3 screw | | | 10 | lbf · in |
| | | | | 1.1 | N · m |

**Notes**

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. Starting $T_J$ = 25 °C, L = 1.5 mH, $R_g$ = 25 Ω, $I_{AS}$ = 23 A (see fig. 12)
c. $I_{SD}$ ≤ 23 A, dI/dt ≤ 650 A/µs, $V_{DD}$ ≤ $V_{DS}$, $T_J$ ≤ 150 °C
d. 1.6 mm from case

## THERMAL RESISTANCE RATINGS

| PARAMETER | SYMBOL | TYP. | MAX. | UNIT |
|---|---|---|---|---|
| Maximum junction-to-ambient | $R_{thJA}$ | - | 40 | °C/W |
| Case-to-sink, flat, greased surface | $R_{thCS}$ | 0.24 | - | |
| Maximum junction-to-case (drain) | $R_{thJC}$ | - | 0.34 | |

## SPECIFICATIONS ($T_J$ = 25 °C, unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|---|---|---|---|---|---|---|---|
| **Static** | | | | | | | |
| Drain-source breakdown voltage | $V_{DS}$ | $V_{GS}$ = 0 V, $I_D$ = 250 µA | | 500 | - | - | V |
| $V_{DS}$ temperature coefficient | $\Delta V_{DS}/T_J$ | Reference to 25 °C, $I_D$ = 1 mA [d] | | - | 0.27 | - | V/°C |
| Gate-source threshold voltage | $V_{GS(th)}$ | $V_{DS}$ = $V_{GS}$, $I_D$ = 250 µA | | 3.0 | - | 5.0 | V |
| Gate-source leakage | $I_{GSS}$ | $V_{GS}$ = ± 30 V | | - | - | ± 100 | nA |
| Zero gate voltage drain current | $I_{DSS}$ | $V_{DS}$ = 500 V, $V_{GS}$ = 0 V | | - | - | 50 | µA |
| | | $V_{DS}$ = 400 V, $V_{GS}$ = 0 V, $T_J$ = 125 °C | | - | - | 2.0 | mA |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}$ = 10 V | $I_D$ = 14 A [b] | - | 0.190 | 0.235 | Ω |
| Forward transconductance | $g_{fs}$ | $V_{DS}$ = 50 V, $I_D$ = 14 A [b] | | - | 9 | - | S |
| **Dynamic** | | | | | | | |
| Input capacitance | $C_{iss}$ | $V_{GS}$ = 0 V, $V_{DS}$ = 25 V, f = 1.0 MHz, see fig. 5 | | - | 3600 | - | pF |
| Output capacitance | $C_{oss}$ | | | - | 380 | - | |
| Reverse transfer capacitance | $C_{rss}$ | | | - | 37 | - | |
| Output capacitance | $C_{oss}$ | $V_{GS}$ = 0 V | $V_{DS}$ = 1.0 V, f = 1.0 MHz | - | 4800 | - | |
| | | | $V_{DS}$ = 400 V, f = 1.0 MHz | - | 100 | - | |
| Effective output capacitance | $C_{oss}$ eff. | | $V_{DS}$ = 0 V to 400 V [c] | - | 220 | - | |
| Effective output capacitance (energy related) | $C_{oss}$ eff. (ER) | | $V_{DS}$ = 0 V to 400 V [d] | - | 160 | - | |
| Internal gate resistance | $R_G$ | f = 1 MHz, open drain | | - | 1.2 | - | Ω |
| Total gate charge | $Q_g$ | $V_{GS}$ = 10 V | $I_D$ = 23 A, $V_{DS}$ = 400 V see fig. 6 and 13 [b] | - | - | 150 | nC |
| Gate-source charge | $Q_{gs}$ | | | - | - | 44 | |
| Gate-drain charge | $Q_{gd}$ | | | - | - | 72 | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD}$ = 250 V, $I_D$ = 23 A $R_g$ = 6.0, $V_{GS}$ = 10 V see fig. 10 [b] | | - | 26 | - | ns |
| Rise time | $t_r$ | | | - | 94 | - | |
| Turn-off delay time | $t_{d(off)}$ | | | - | 53 | - | |
| Fall time | $t_f$ | | | - | 45 | - | |
| **Drain-Source Body Diode Characteristics** | | | | | | | |
| Continuous source-drain diode current | $I_S$ | MOSFET symbol showing the integral reverse p - n junction diode  | | - | - | 23 | A |
| Pulsed diode forward current [a] | $I_{SM}$ | | | - | - | 92 | |
| Body diode voltage | $V_{SD}$ | $T_J$ = 25 °C, $I_S$ = 14 A, $V_{GS}$ = 0 V [b] | | - | - | 1.5 | V |
| Body diode reverse recovery time | $t_{rr}$ | $T_J$ = 25 °C | $I_F$ = 23 A, dI/dt = 100 A/µs [b] | - | 170 | 250 | ns |
| | | $T_J$ = 125 °C | | - | 220 | 330 | |
| Body diode reverse recovery charge | $Q_{rr}$ | $T_J$ = 25 °C | | - | 560 | 840 | µC |
| | | $T_J$ =1 25 °C | | - | 980 | 1500 | |
| Reverse recovery current | $I_{RRM}$ | $T_J$ = 25 °C | | - | 7.6 | 11 | A |
| Forward turn-on time | $t_{on}$ | Intrinsic turn-on time is negligible (turn-on is dominated by $L_S$ and $L_D$) | | | | | |

**Notes**

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. Pulse width ≤ 300 µs; duty cycle ≤ 2 %
c. $C_{OSS}$ eff. is a fixed capacitance that gives the same charging time as $C_{OSS}$ while $V_{DS}$ is rising from 0 % to 80 % $V_{DS}$
d. $C_{oss}$ eff. (ER) is a fixed capacitance that stores the same energy time as $C_{OSS}$ while $V_{DS}$ is rising from 0 % to 80 % $V_{DS}$

## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

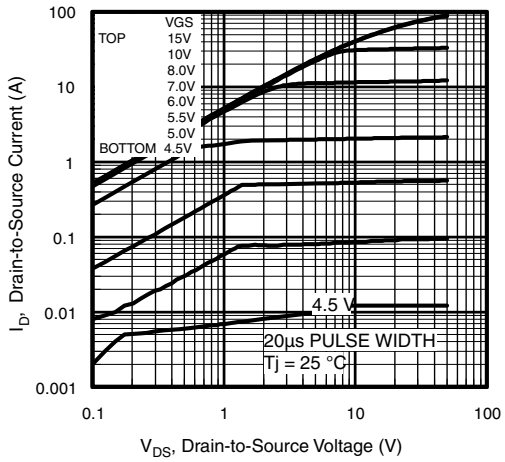



**Fig. 1 - Typical Output Characteristics**

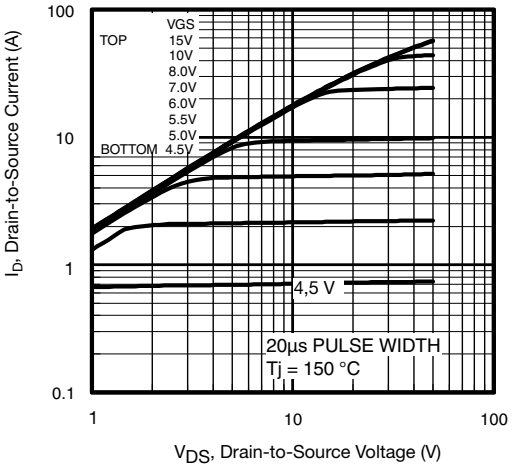



**Fig. 2 - Typical Output Characteristics**

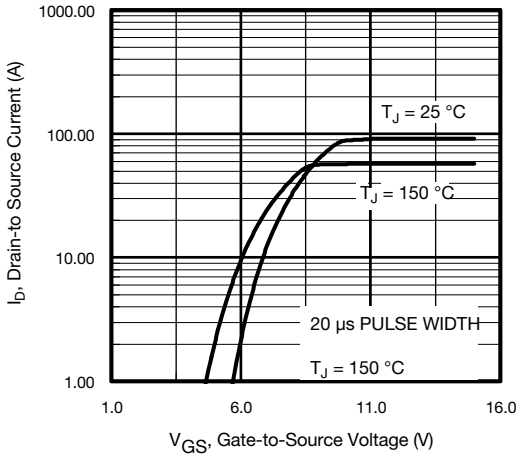



**Fig. 3 - Typical Transfer Characteristics**

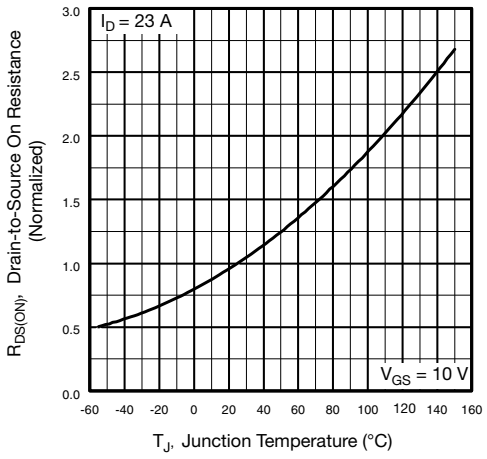



**Fig. 4 - Normalized On-Resistance vs. Temperature**

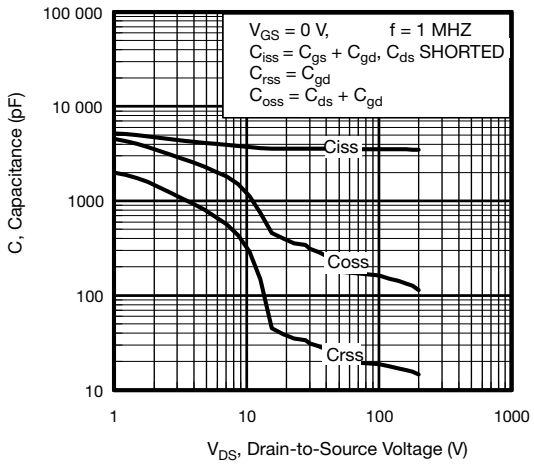



**Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage**

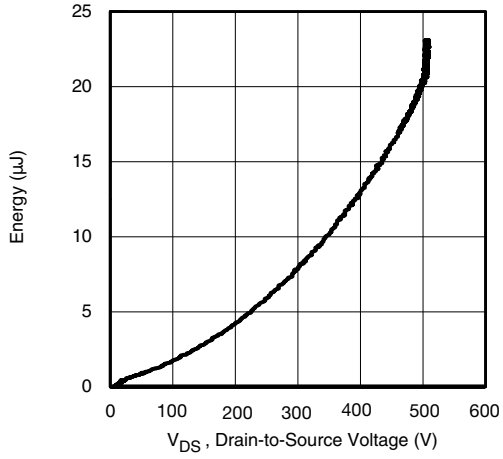



**Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage**

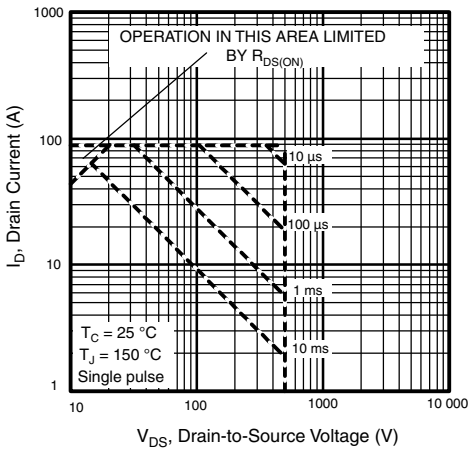



**Fig. 7 - Maximum Safe Operating Area**

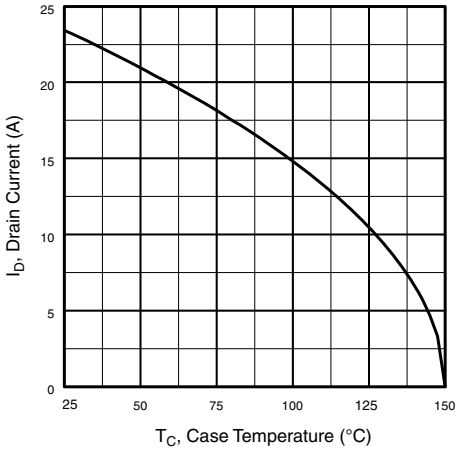



**Fig. 10 - Maximum Drain Current vs. Case Temperature**

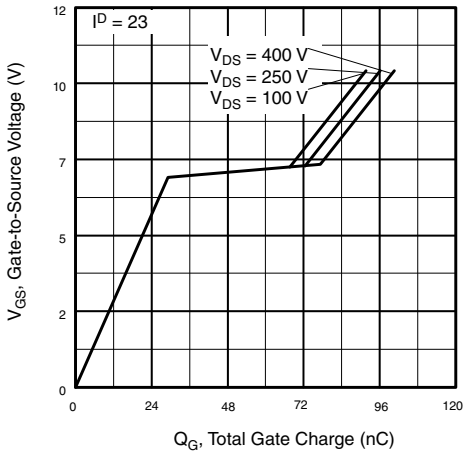



**Fig. 8 - Typical Gate Charge vs. Gate-to-Source Voltage**

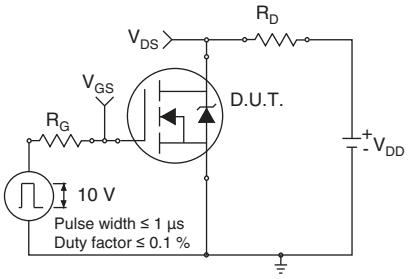



**Fig. 11a - Switching Time Test Circuit**

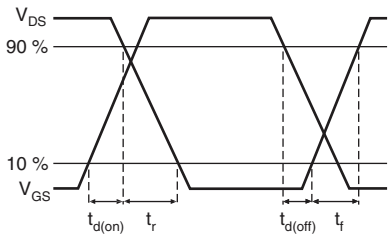



**Fig. 11b - Switching Time Waveforms**

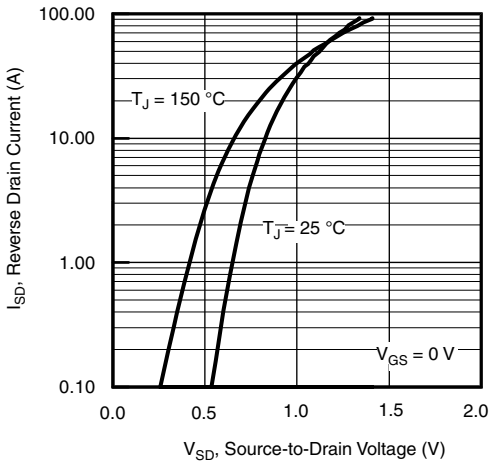



**Fig. 9 - Typical Source-Drain Diode Forward Voltage**

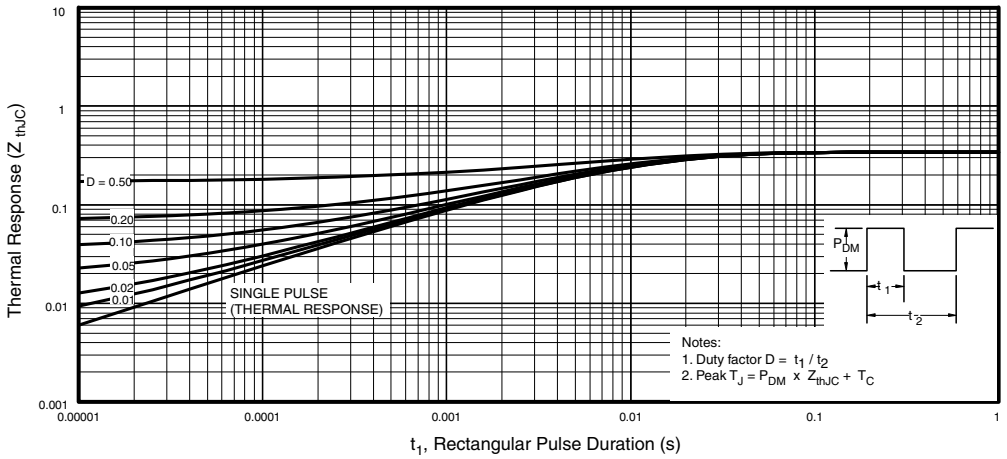



**Fig. 12 - Maximum Effective Transient Thermal Impedance, Junction-to-Case**

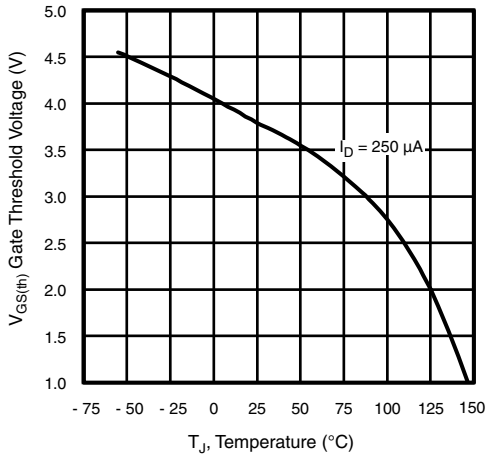



**Fig. 13 - Threshold Voltage vs. Temperature**

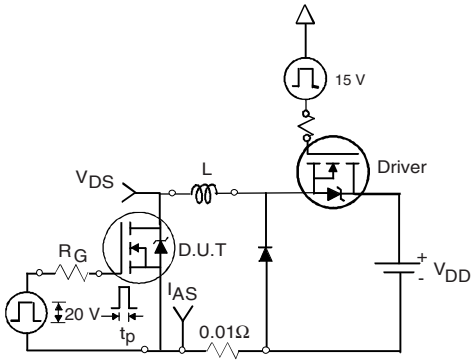



**Fig. 15a - Unclamped Inductive Test Circuit**

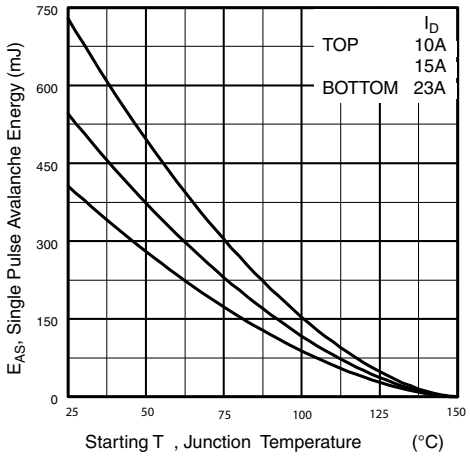



**Fig. 14 - Maximum Avalanche Energy s. Drain Current**

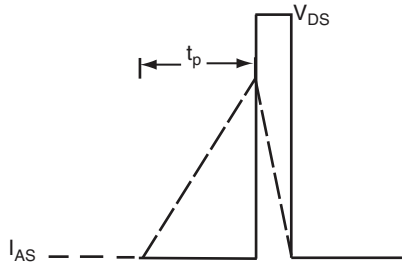



**Fig. 15b - Unclamped Inductive Waveforms**

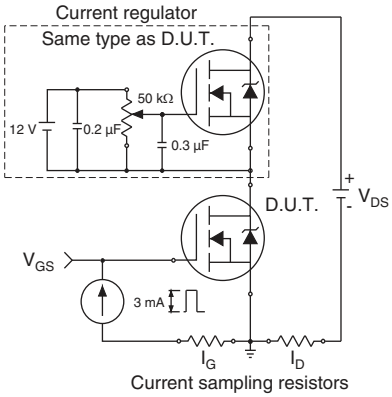



**Fig. 16a - Gate Charge Test Circuit**

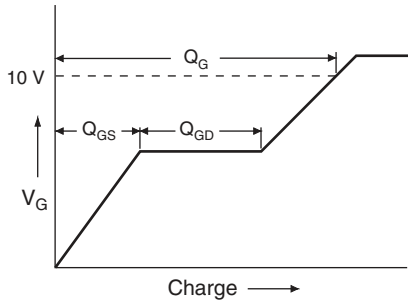
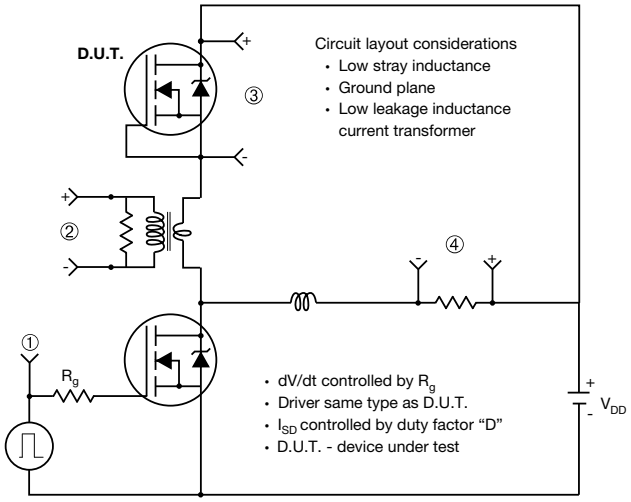
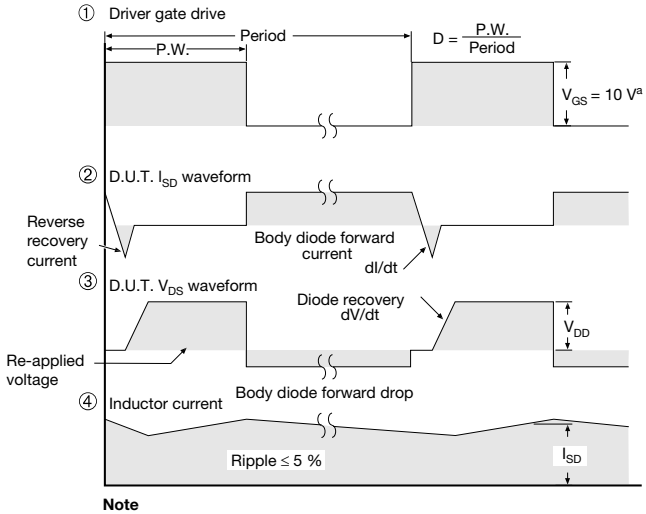



**Fig. 16b - Basic Gate Charge Waveform**

**Peak Diode Recovery dV/dt Test Circuit**




**Note**

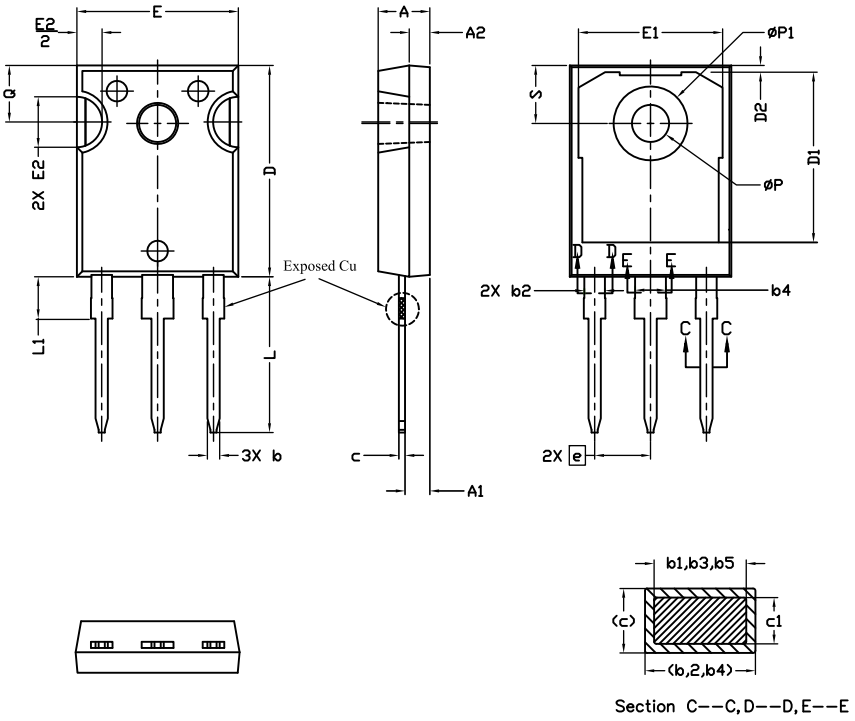
a. $V_{GS}$ = 5 V for logic level devices

**Fig. 17 - For N-Channel**

*Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?91209.*

# TO-247AC (High Voltage)

## VERSION 1: FACILITY CODE = 9









Section C--C, D--D, E--E

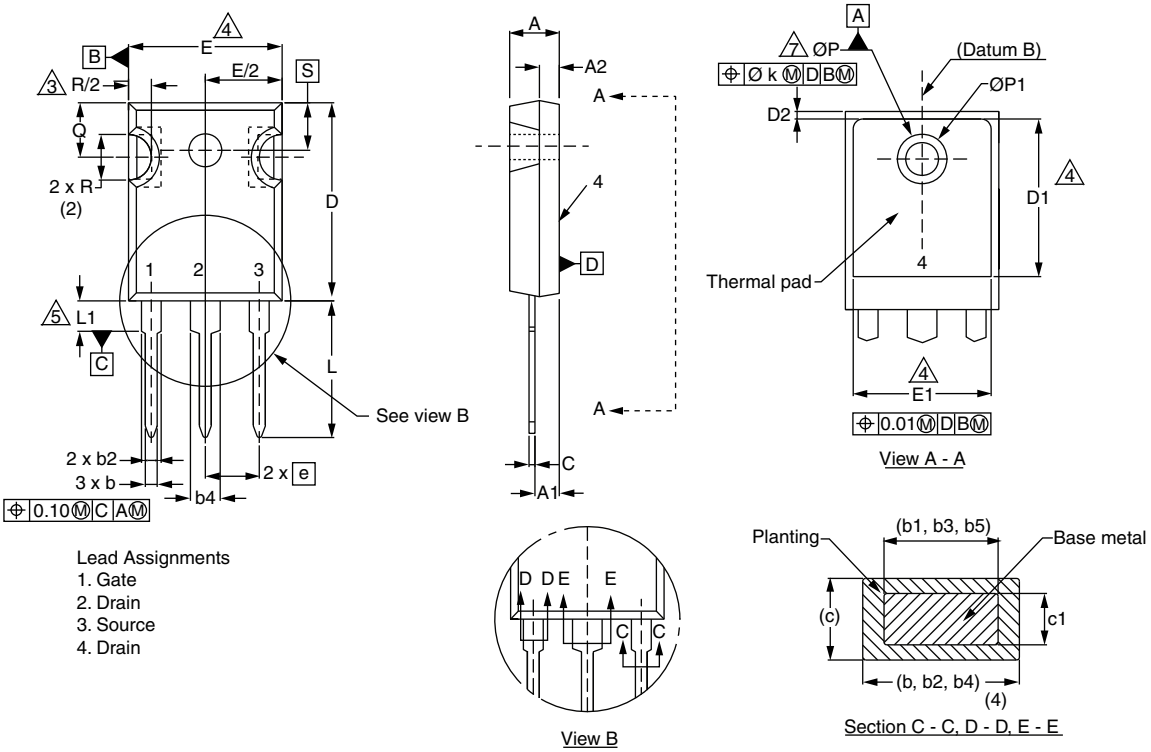
| | MILLIMETERS | | |
|---|---|---|---|
| DIM. | MIN. | MAX. | NOTES |
| A | 4.83 | 5.21 | |
| A1 | 2.29 | 2.55 | |
| A2 | 1.50 | 2.49 | |
| b | 1.12 | 1.33 | |
| b1 | 1.12 | 1.28 | |
| b2 | 1.91 | 2.39 | 6 |
| b3 | 1.91 | 2.34 | |
| b4 | 2.87 | 3.22 | 6, 8 |
| b5 | 2.87 | 3.18 | |
| c | 0.55 | 0.69 | 6 |
| c1 | 0.55 | 0.65 | |
| D | 20.40 | 20.70 | 4 |

| | MILLIMETERS | | |
|---|---|---|---|
| DIM. | MIN. | MAX. | NOTES |
| D1 | 16.25 | 16.85 | 5 |
| D2 | 0.56 | 0.76 | |
| E | 15.50 | 15.87 | 4 |
| E1 | 13.46 | 14.16 | 5 |
| E2 | 4.52 | 5.49 | 3 |
| e | 5.44 BSC | | |
| L | 14.90 | 15.40 | |
| L1 | 3.96 | 4.16 | 6 |
| Ø P | 3.56 | 3.65 | 7 |
| Ø P1 | 7.19 ref. | | |
| Q | 5.31 | 5.69 | |
| S | 5.54 | 5.74 | |

**Notes**

(1) Package reference: JEDEC® TO247, variation AC
(2) All dimensions are in mm
(3) Slot required, notch may be rounded
(4) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These dimensions are measured at the outermost extremes of the plastic body
(5) Thermal pad contour optional with dimensions D1 and E1
(6) Lead finish uncontrolled in L1
(7) Ø P to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 3.91 mm
(8) Dimension b2 and b4 does not include dambar protrusion. Allowable dambar protrusion shall be 0.1 mm total in excess of b2 and b4 dimension at maximum material condition

## VERSION 2: FACILITY CODE = Y




Lead Assignments
1. Gate
2. Drain
3. Source
4. Drain

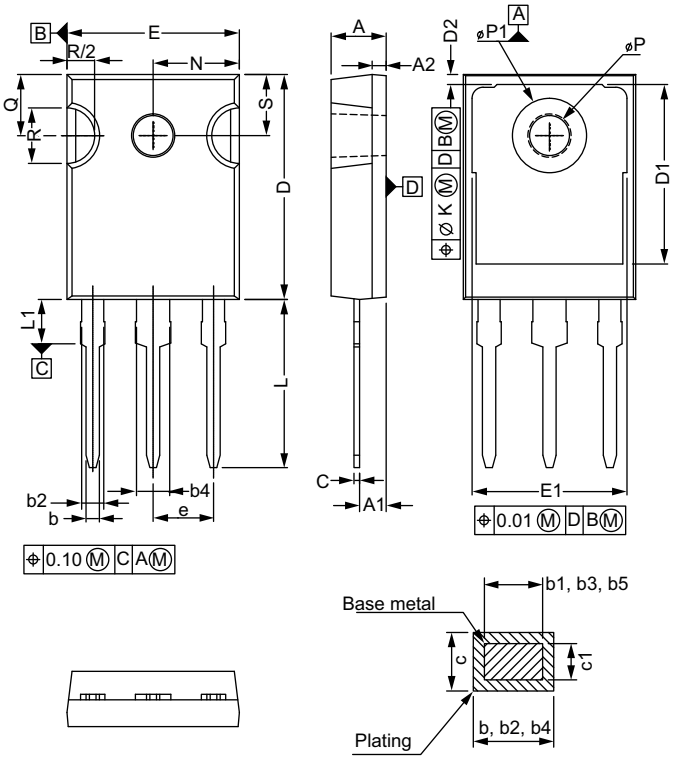
| | MILLIMETERS | | |
|---|---|---|---|
| DIM. | MIN. | MAX. | NOTES |
| A | 4.58 | 5.31 | |
| A1 | 2.21 | 2.59 | |
| A2 | 1.17 | 2.49 | |
| b | 0.99 | 1.40 | |
| b1 | 0.99 | 1.35 | |
| b2 | 1.53 | 2.39 | |
| b3 | 1.65 | 2.37 | |
| b4 | 2.42 | 3.43 | |
| b5 | 2.59 | 3.38 | |
| c | 0.38 | 0.86 | |
| c1 | 0.38 | 0.76 | |
| D | 19.71 | 20.82 | |
| D1 | 13.08 | - | |

| | MILLIMETERS | | |
|---|---|---|---|
| DIM. | MIN. | MAX. | NOTES |
| D2 | 0.51 | 1.30 | |
| E | 15.29 | 15.87 | |
| E1 | 13.72 | - | |
| e | 5.46 BSC | | |
| Ø k | 0.254 | | |
| L | 14.20 | 16.25 | |
| L1 | 3.71 | 4.29 | |
| Ø P | 3.51 | 3.66 | |
| Ø P1 | - | 7.39 | |
| Q | 5.31 | 5.69 | |
| R | 4.52 | 5.49 | |
| S | 5.51 BSC | | |
| | | | |

**Notes**

(1) Dimensioning and tolerancing per ASME Y14.5M-1994
(2) Contour of slot optional
(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
(4) Thermal pad contour optional with dimensions D1 and E1
(5) Lead finish uncontrolled in L1
(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
(7) Outline conforms to JEDEC outline TO-247 with exception of dimension c

## VERSION 3: FACILITY CODE = N




| | MILLIMETERS | |
|---|---|---|
| DIM. | MIN. | MAX. |
| A | 4.65 | 5.31 |
| A1 | 2.21 | 2.59 |
| A2 | 1.17 | 1.37 |
| b | 0.99 | 1.40 |
| b1 | 0.99 | 1.35 |
| b2 | 1.65 | 2.39 |
| b3 | 1.65 | 2.34 |
| b4 | 2.59 | 3.43 |
| b5 | 2.59 | 3.38 |
| c | 0.38 | 0.89 |
| c1 | 0.38 | 0.84 |
| D | 19.71 | 20.70 |
| D1 | 13.08 | - |

| | MILLIMETERS | |
|---|---|---|
| DIM. | MIN. | MAX. |
| D2 | 0.51 | 1.35 |
| E | 15.29 | 15.87 |
| E1 | 13.46 | - |
| e | 5.46 BSC | |
| k | 0.254 | |
| L | 14.20 | 16.10 |
| L1 | 3.71 | 4.29 |
| N | 7.62 BSC | |
| P | 3.56 | 3.66 |
| P1 | - | 7.39 |
| Q | 5.31 | 5.69 |
| R | 4.52 | 5.49 |
| S | 5.51 BSC | |

ECN: E20-0545-Rev. F, 19-Oct-2020
DWG: 5971

**Notes**

(1) Dimensioning and tolerancing per ASME Y14.5M-1994
(2) Contour of slot optional
(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
(4) Thermal pad contour optional with dimensions D1 and E1
(5) Lead finish uncontrolled in L1
(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

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